

T495C337K006ZGE200

Obsolete

Tantalum, MnO₂ Tantalum, 330 uF, 10%, 6.3 VDC, SMD, Molded, Low ESR, Surge Robust, 200 mOhms, 6032, 2.8mm



Dimensions

Footprint	6032
L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1.8mm TYP

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	750

General Information

Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust
RoHS	Yes
Termination	Gold
AEC-Q200	No
Notes	Old Part Number [Obsolete] Was B45106C3379K207.

Specifications

Capacitance	330 uF
Capacitance Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	18%
Failure Rate	N/A
ESR	0.2 Ohms (100kHz)
Ripple Current	740 mAmps (25C), 666 mAmps (85C), 296 mAmps (125C)
Leakage Current	20.8 uA